NSN 5961-00-408-0880

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View Online at https://aerobasegroup.com/nsn/5961-00-408-0880 **Inclosure Material:** Metal **Overall Length:** Between 0.320 inches and 0.468 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 80.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 amperes source cutoff current and 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.3 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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